

Description

This bipolar junction transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

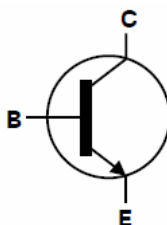
- $BV_{CEO} > 25V$
- $I_C = 50mA$ Continuous Collector Current
- Designed for VHF/UHF Amplifier Applications and High Output VHF Oscillators
- High Current Gain Bandwidth Product
- Ideal for Mixer and RF Amplifier Applications with Collector Currents in the 100 μA to 30mA Range
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Mechanical Data

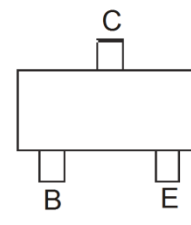
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.008 grams (Approximate)



Top View



Device Symbol



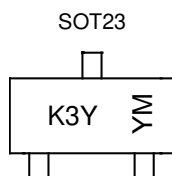
Top View Pin-Out

Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
MMBTH10Q-7-F	Automotive	K3Y	7	8	3000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to <https://www.diodes.com/quality/>.
 5. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



K3Y = Product Type Marking Code
 YM = Date Code Marking
 Y = Year ex: F = 2018
 M = Month ex: 9 = September

Date Code Key

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	F	G	H	I	J	K	L	M	N	O	P	Q

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

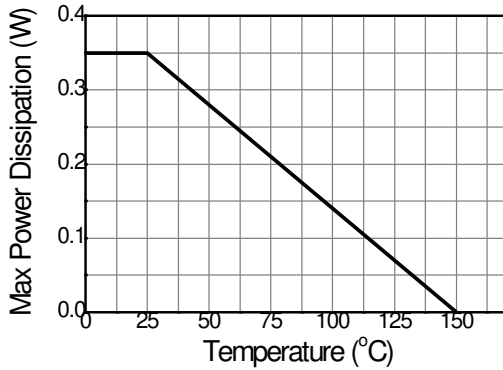
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CB0}	30	V
Collector-Emitter Voltage	V_{CEO}	25	V
Emitter-Base Voltage	V_{EBO}	3	V
Collector Current	I_C	50	mA

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

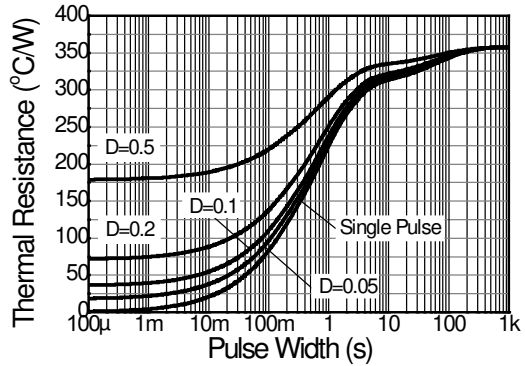
Characteristic	Symbol	Value	Unit
Power Dissipation	P_D	(Note 6)	310
		(Note 7)	350
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	(Note 6)	403
		(Note 7)	357
Thermal Resistance, Junction to Leads	$R_{\theta JL}$	350	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	$^\circ\text{C}$

- Notes:
- 6. For a device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper; device is measured under still air conditions whilst operating in a steady-state.
 - 7. Same as Note 6, except mounted on 15mm x 15mm 1oz copper.
 - 8. Thermal resistance from junction to solder-point (at the end of the collector lead).

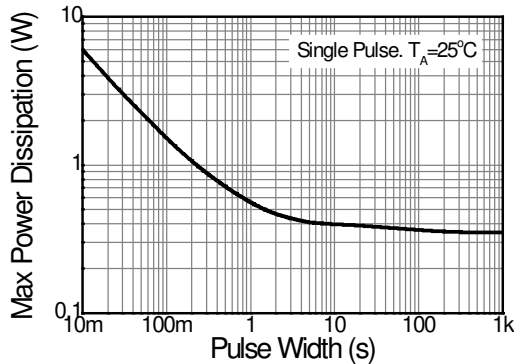
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Collector-Base Breakdown Voltage	BV _{CBO}	30	—	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	25	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	3	—	—	V	I _C = 100μA
Collector-Base Cut-Off Current	I _{CBO}	—	—	100	nA	V _{CB} = 25V
Emitter-Base Cut-Off Current	I _{EBO}	—	—	100	nA	V _{EB} = 2V
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h _{FE}	60	—	—	—	V _{CE} = 10V, I _C = 4mA
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	—	0.5	V	I _C = 4mA, I _B = 400μA
Base-Emitter Voltage	V _{BE(SAT)}	—	—	0.95	V	I _C = 4mA, I _B = 400μA
Base-Emitter Turn-on Voltage	V _{BE(ON)}	—	—	0.95	V	V _{CE} = 10V, I _C = 4mA
SMALL SIGNAL CHARACTERISTICS						
Current Gain Bandwidth Product	f _T	650	—	—	MHz	V _{CE} = 10V, I _C = 4mA, f = 100MHz
Collector-Base Capacitance	C _{CBO}	—	—	0.7	pF	V _{CB} = 10V, f = 1MHz
Collector-Base Feedback Capacitance	C _{RB0}	—	—	0.65	pF	V _{CB} = 10V, f = 1MHz
Collector-Base Time Constant	R _b 'C _c	—	—	9	ps	V _{CB} = 10V, f = 31.8MHz, I _C = 4mA

Note 9: Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

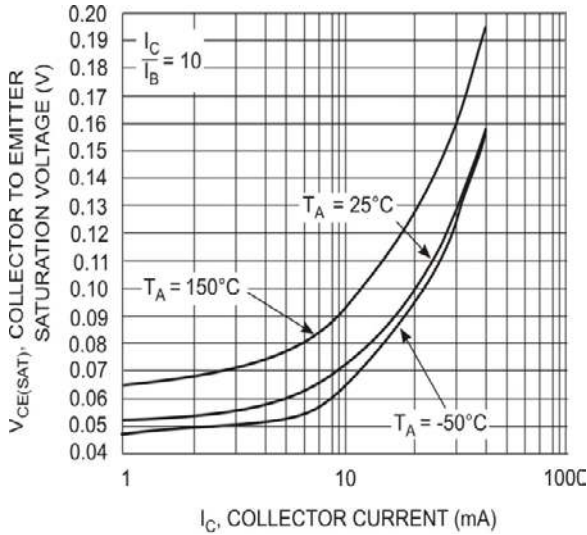


Fig. 1 Collector Emitter Saturation Voltage vs. Collector Current

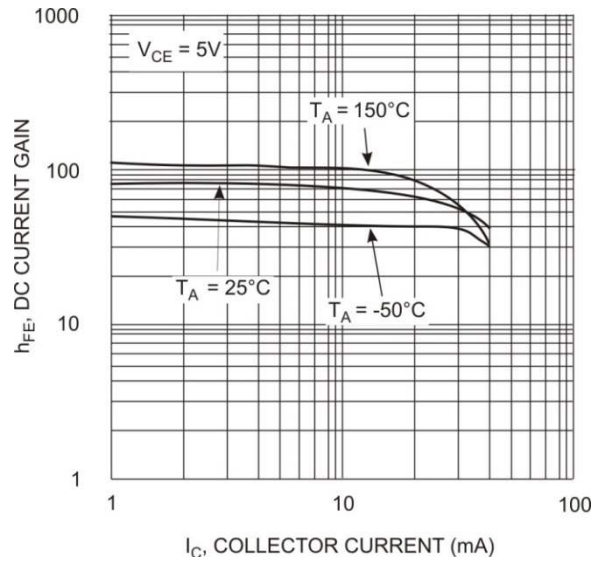


Fig. 2 DC Current Gain vs. Collector Current

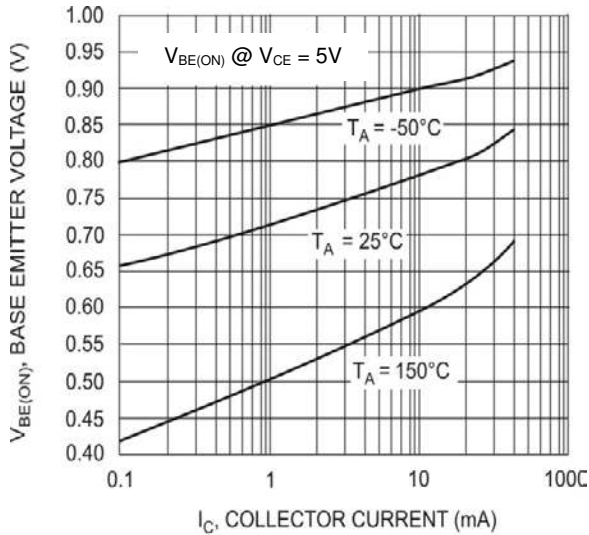


Fig. 3 Base Emitter Voltage vs. Collector Current

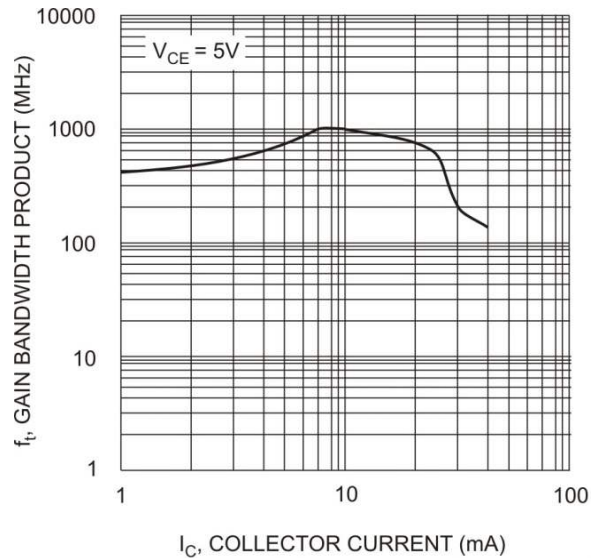
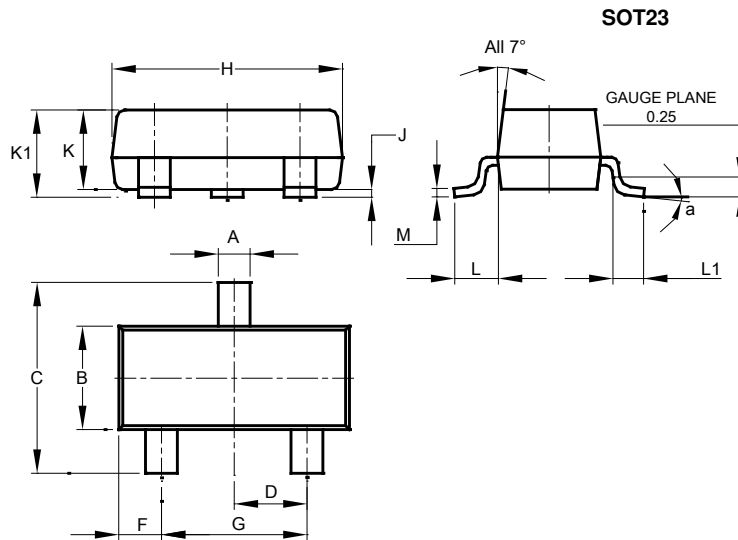


Fig. 4 Gain Bandwidth Product vs. Collector Current

Package Outline Dimensions

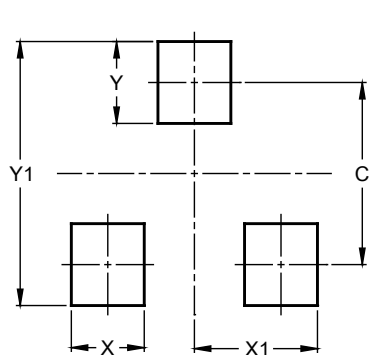
Please see <http://www.diodes.com/package-outlines.html> for the latest version.



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

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